1. General description

NPN high power bipolar transistor in a power DPAK, TO-252 (SOT428C) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- High thermal power dissipation capability
- High energy efficiency due to less heat generation
- · Electrically similar to popular MJD148 series
- Low collector emitter saturation voltage
- Fast switching speeds

3. Applications

- Power management
- Load switch
- · Linear mode voltage regulator
- Constant current drive backlighting application
- Motor drive
- · Relay replacement

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	45	V
I _C	collector current		-	-	4	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	7	Α
h _{FE}	DC current gain	V_{CE} = 1 V; I_{C} = 0.5 A; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	85	-	375	
		V_{CE} = 1 V; I_{C} = 3 A; pulsed; $t_{p} \le 300 \ \mu s$; δ ≤ 0.02; T_{amb} = 25 °C	30	-	-	



45 V, 4 A NPN high power bipolar transistor

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	mb	Ë
2	С	collector		в -[**
3	Е	emitter		C; mb
mb	С	mounting base; connected to collector	DPAK (SOT428C)	aaa-029889

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
MJD148		Plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428C		

7. Marking

Table 4. Marking codes

Type number	Marking code
MJD148	MJD148

8. Limiting values

Table 5. Limiting values

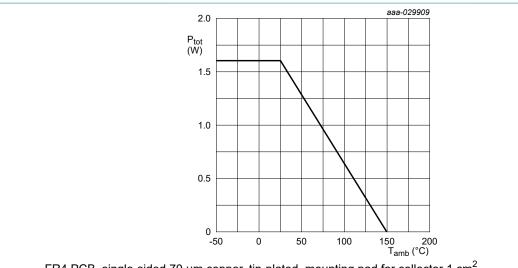
In accordance with the Absolute Maximum Rating System (IEC601134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CEO}	collector-emitter voltage	open base		-	45	V
V_{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	4	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	7	Α
P _{tot}	total power dissipation	T _{mb} ≤ 25 °C	[1]	-	15	W
		T _{amb} ≤ 25 °C	[2]	-	1.6	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Total power dissipation junction to mounting base.

^[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided 70 μm copper, tin-plated mounting pad for collector 1 cm².

45 V, 4 A NPN high power bipolar transistor



FR4 PCB, single-sided 70 µm copper, tin-plated, mounting pad for collector 1 cm².

Fig. 1. Power derating curves SOT428C

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	79	K/W
R _{th(j-mb)}	thermal resistance from junction to mounting base			-	-	9	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided 70 µm copper, tin-plated mounting pad for collector 1 cm².

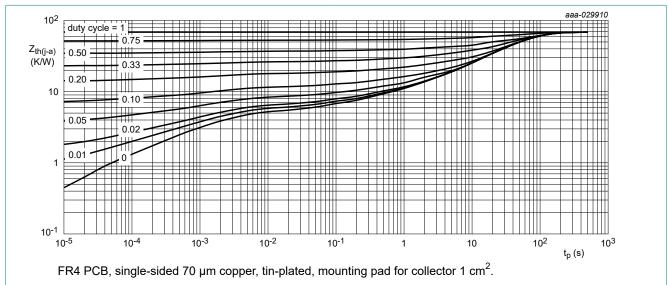


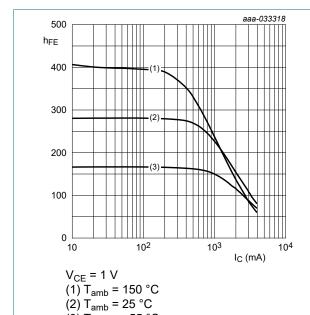
Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

45 V, 4 A NPN high power bipolar transistor

10. Characteristics

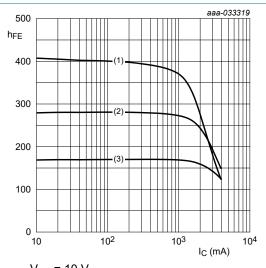
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CES}	collector-emitter cut-off current	V _{CE} = 45 V; V _{BE} = 0 V; T _{amb} = 25 °C	-	-	1	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C	-	-	1	μΑ
h _{FE}	DC current gain	V_{CE} = 5 V; I_{C} = 10 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	40	-	-	
		V_{CE} = 1 V; I_{C} = 0.5 A; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	85	-	375	
		V_{CE} = 1 V; I_{C} = 2 A; pulsed; $t_{p} \le 300 \ \mu s$; δ ≤ 0.02; T_{amb} = 25 °C	50	-	-	
		V_{CE} = 1 V; I_{C} = 3 A; pulsed; $t_{p} \le 300 \ \mu s$; $\delta \le 0.02$; T_{amb} = 25 °C	30	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = 2 A; I_B = 0.2 A; pulsed; $t_p \le 300 \ \mu s$; δ ≤ 0.02; T_{amb} = 25 °C	-	-	0.5	V
V _{BE}	base-emitter voltage	V_{CE} = 1 V; I_{C} = 2 A; pulsed; $t_{p} \le 300 \mu s$; T_{amb} = 25 °C	-	-	1.1	V
f _T	transition frequency	V_{CE} = 1 V; I_{C} = 250 mA; f = 100 MHz; T_{amb} = 25 °C	3	-	-	MHz



DC current gain as a function of collector Fig. 3. current; typical values

(3) $T_{amb} = -55 \, ^{\circ}C$



V_{CE} = 10 V (1) T_{amb} = 150 °C (2) T_{amb} = 25 °C

(3) $T_{amb} = -55 \, ^{\circ}C$

DC current gain as a function of collector Fig. 4. current; typical values

45 V, 4 A NPN high power bipolar transistor

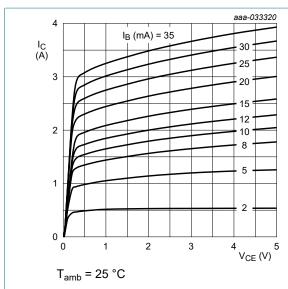
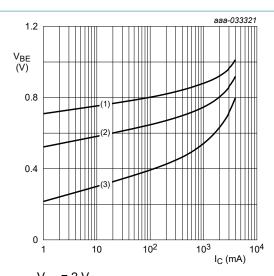
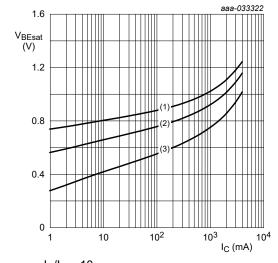


Fig. 5. Collector current as a function of collectoremitter voltage; typical values



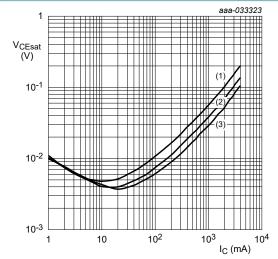
V_{CE} = 2 V (1) T_{amb} = -55 °C (2) T_{amb} = 25 °C (3) T_{amb} = 150 °C

Fig. 6. Base-emitter voltage as a function of collector current; typical values



 $I_C/I_B = 10$ (1) $T_{amb} = -55$ °C (2) $T_{amb} = 25$ °C (3) $T_{amb} = 150$ °C

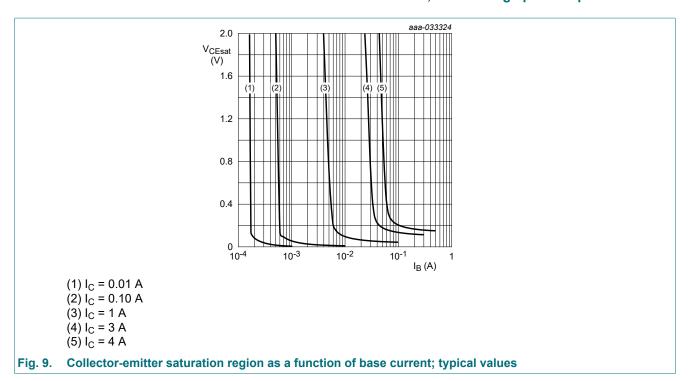
Fig. 7. Base-emitter saturation voltage as a function of collector current; typical values



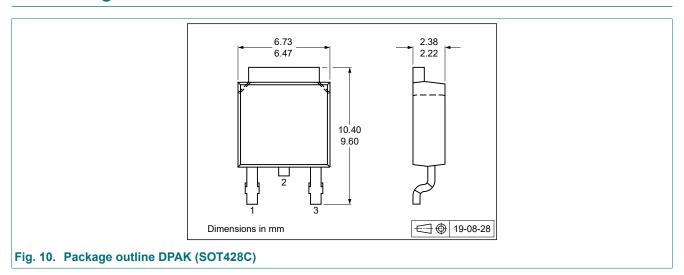
 $I_{\rm C}/I_{\rm B} = 10$ (1) $T_{\rm amb} = 150~{\rm ^{\circ}C}$ (2) $T_{\rm amb} = 25~{\rm ^{\circ}C}$ (3) $T_{\rm amb} = -55~{\rm ^{\circ}C}$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

45 V, 4 A NPN high power bipolar transistor

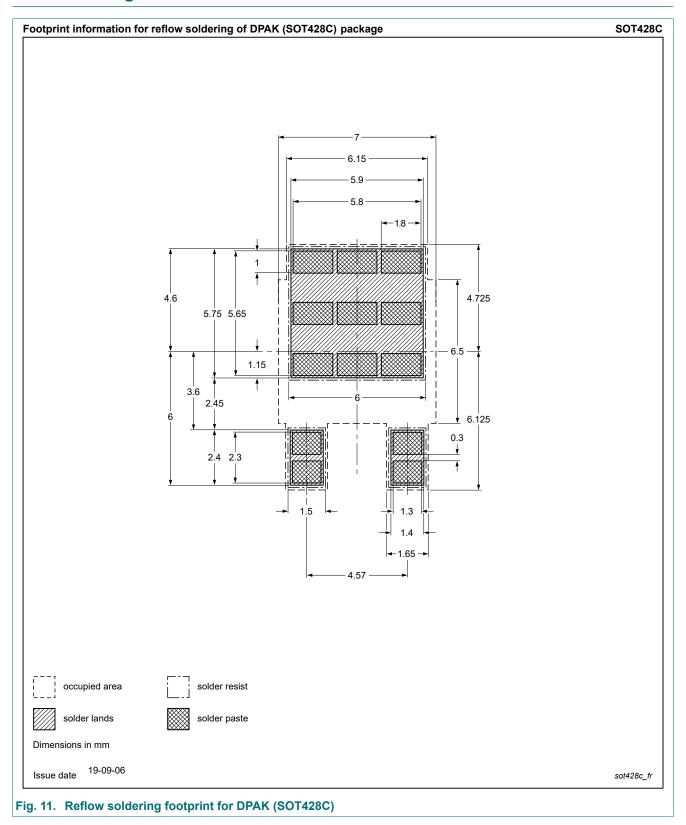


11. Package outline



45 V, 4 A NPN high power bipolar transistor

12. Soldering



45 V, 4 A NPN high power bipolar transistor

13. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
MJD148 v.1	20210426	Product data sheet	-	-

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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45 V, 4 A NPN high power bipolar transistor

Contents

1.	General description	. 1
2.	Features and benefits	. 1
3.	Applications	. 1
4.	Quick reference data	. 1
5.	Pinning information	.2
6.	Ordering information	. 2
7.	Marking	. 2
8.	Limiting values	. 2
9.	Thermal characteristics	. 3
10.	Characteristics	. 4
11.	Package outline	. 6
12.	Soldering	. 7
13.	Revision history	.8
14.	Legal information	9

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